

LM136-5.0, LM236-5.0, LM336-5.0 5.0V Reference Diode

Check for Samples: LM136-5.0, LM236-5.0, LM336-5.0

FEATURES

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- Adjustable 4V to 6V
- **Low Temperature Coefficient**
- Wide Operating Current of 600 µA to 10 mA
- 0.6Ω Dynamic Impedance
- ± 1% Initial Tolerance Available
- **Specified Temperature Stability**
- **Easily Trimmed for Minimum Temperature Drift**
- **Fast Turn-on**
- Three Lead Transistor Package

DESCRIPTION

LM136-5.0/LM236-5.0/LM336-5.0 circuits are precision 5.0V shunt regulator diodes. These monolithic IC voltage references operate as a low temperature coefficient 5.0V zener with 0.6Ω dynamic impedance. A third terminal on the LM136-5.0 allows the reference voltage and temperature coefficient to be trimmed easily.

The LM136-5.0 series is useful as a precision 5.0V low voltage reference for digital voltmeters, power supplies or op amp circuitry. The 5.0V makes it convenient to obtain a stable reference from low voltage supplies. Further, since the LM136-5.0 operates as a shunt regulator, it can be used as either a positive or negative voltage reference.

The LM136-5.0 is rated for operation over -55°C to +125°C while the LM236-5.0 is rated over a -25°C to +85°C temperature range. The LM336-5.0 is rated for operation over a 0°C to +70°C temperature range. See the Connection Diagrams for available packages. For applications requiring 2.5V see LM136-2.5.

Connection Diagrams



Figure 1. TO-92 Plastic Package (Bottom View)

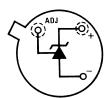


Figure 2. TO Metal Can Package (Bottom View)

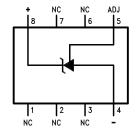


Figure 3. SOIC Package

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Typical Applications

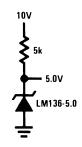
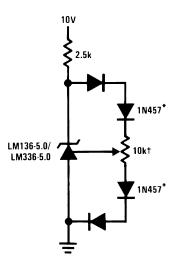
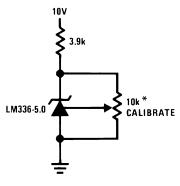


Figure 4. 5.0V Reference



- † Adjust to 5.00V * Any silicon signal diode

Figure 5. 5.0V Reference with Minimum **Temperature Coefficient**



^{*} Does not affect temperature coefficient

Figure 6. Trimmed 4V to 6V Reference with Temperature Coefficient Independent of Breakdown Voltage





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS (1)

Reverse Current	15	mA
Forward Current	10	mA
Storage Temperature	-60 to +150	°C
Operating Temperature Range (2)		
LM136-5.0	-55 to +150	°C
LM236-5.0	−25 to +85	°C
LM336-5.0	0 to +70	°C
Soldering Information		
TO-92 Package (10 sec.)	260	°C
TO Package (10 sec.)	300	°C
SOIC Package		
Vapor Phase (60 sec.)	215	°C
Infrared (15 sec.)	220	°C

⁽¹⁾ Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Electrical specifications do not apply when operating the device beyond its specified operating conditions.

THERMAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

	LM136	150°C	
	LM236	125°C	
	LM336	100°C	
Thermal Resistance	TO-92	то	SOIC-8
θ _{ja} (Junction to Ambient)	180°C/W (0.4" Leads)	440°C/W	165°C/W
	170°C/W (0.125" Leads)		
θ_{ja} (Junction to Case)	N/A	80°C/W	N/A

ELECTRICAL CHARACTERISTICS

		LM136	A-5.0/LM2	36A-5.0	I)		
Parameter	Conditions	LM13	6-5.0/LM2	36-5.0		LM336-5.0		Units
		Min	Тур	Max	Min	Тур	Max	
Reverse Breakdown Voltage	T _A =25°C, I _R =1 mA							
	LM136-5.0/LM236-5.0/LM336-5.0			5.1	4.8	5.00	5.2	V
	LM136A-5.0/LM236A-5.0, LM336B-5.0	4.95	5.00	5.05	4.90	5.00	5.1	V
Reverse Breakdown Change			6	12		6	20	mV
With Current	600 μA≤l _R ≤10 mA							
Reverse Dynamic Impedance			0.6	1.2		0.6	2	Ω
Temperature Stability	V _R Adjusted 5.00V							
(2)	I _R =1 mA, (Figure 15)							
	0°C≤T _A ≤70°C (LM336-5.0)					4	12	mV

⁽¹⁾ Unless otherwise specified, the LM136-5.0 is specified from −55°C≤T_A≤+125°C, the LM236-5.0 from −25°C≤T_A≤+85°C and the LM336-5.0 from 0°C≤T_A≤+70°C.

⁽²⁾ For elevated temperature operation, T_i max see THERMAL CHARACTERISTICS

⁽²⁾ Temperature stability for the LM336 and LM236 family is specified by design. Design limits are specified (but not 100% percent production tested) over the indicated temperature and supply voltage ranges. These limits are not used to calculate outgoing quality levels. Stability is defined as the maximum charge in V_{REF} from 25°C to T_A(min) or T_A(max).



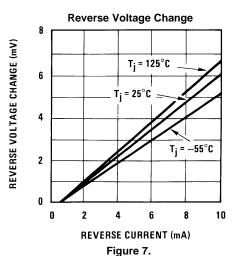
ELECTRICAL CHARACTERISTICS (continued)

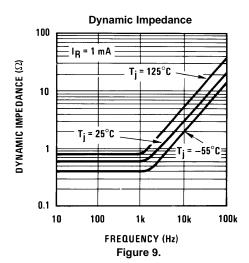
(1)

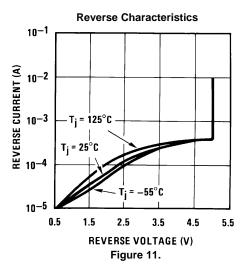
		LM136	A-5.0/LM2	36A-5.0		LM336B-5.0				
Parameter	Conditions	LM13	36-5.0/LM2	36-5.0		LM336-5.0)	Units		
		Min	Тур	Max	Min	Тур	Max			
	-25°C≤T _A ≤+85°C (LM236-5.0)		7	18				mV		
	-55°C≤T _A ≤+125°C (LM136-5.0)		20	36				mV		
Reverse Breakdown Change	600 μA≤I _R ≤10 mA		6	17		6	24	mV		
With Current										
Adjustment Range	Circuit of Figure 14		±1			±1		V		
Reverse Dynamic Impedance	I _R = 1 mA		0.8	1.6		0.8	2.5	Ω		
Long Term Stability	$T_A=25$ °C±0.1°C, $I_R=1$ mA, $t = 1000$ hrs		20			20		ppm		

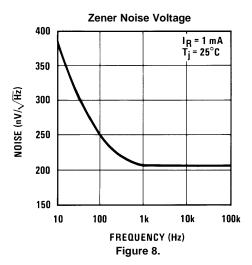


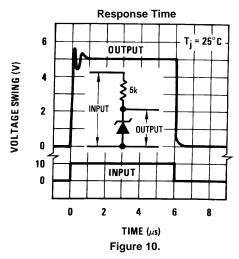
TYPICAL PERFORMANCE CHARACTERISTICS

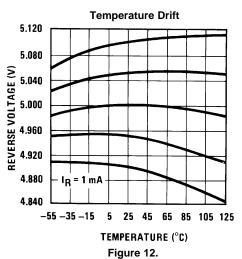






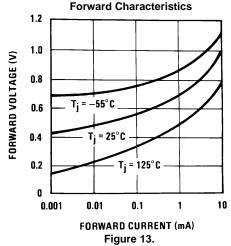








TYPICAL PERFORMANCE CHARACTERISTICS (continued) Forward Characteristics





APPLICATION HINTS

The LM136-5.0 series voltage references are much easier to use than ordinary zener diodes. Their low impedance and wide operating current range simplify biasing in almost any circuit. Further, either the breakdown voltage or the temperature coefficient can be adjusted to optimize circuit performance.

Figure 14 shows an LM136-5.0 with a 10k potentiometer for adjusting the reverse breakdown voltage. With the addition of R1 the breakdown voltage can be adjusted without affecting the temperature coefficient of the device. The adjustment range is usually sufficient to adjust for both the initial device tolerance and inaccuracies in buffer circuitry.

If minimum temperature coefficient is desired, four diodes can be added in series with the adjustment potentiometer as shown in Figure 15. When the device is adjusted to 5.00V the temperature coefficient is minimized. Almost any silicon signal diode can be used for this purpose such as a 1N914, 1N4148 or a 1N457. For proper temperature compensation the diodes should be in the same thermal environment as the LM136-5.0. It is usually sufficient to mount the diodes near the LM136-5.0 on the printed circuit board. The absolute resistance of the network is not critical and any value from 2k to 20k will work. Because of the wide adjustment range, fixed resistors should be connected in series with the pot to make pot setting less critical.

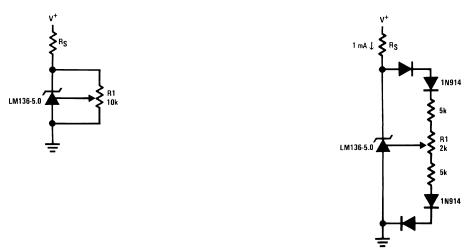
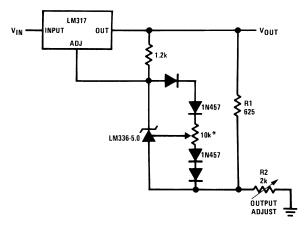


Figure 14. LM136-5.0 with Pot for Adjustment of Breakdown Voltage (Trim Range = ±1.0V Typical)

Figure 15. Temperature Coefficient Adjustment (Trim Range = ±0.5V Typical)

Typical Applications



^{*} Adjust for 6.25V across R1

Figure 16. Precision Power Regulator with Low Temperature Coefficient



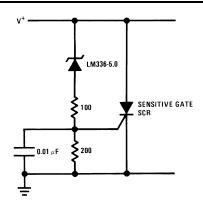
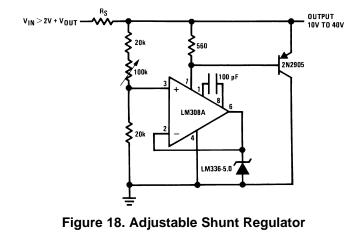


Figure 17. 5V Crowbar



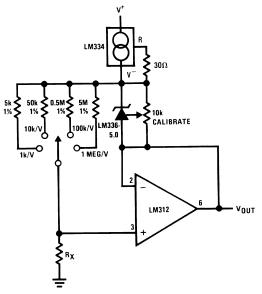


Figure 19. Linear Ohmmeter

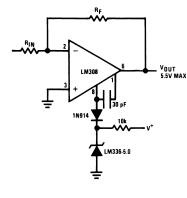


Figure 20. Op Amp with Output Clamped

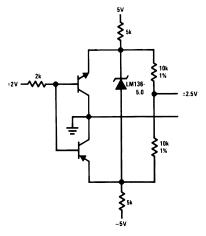


Figure 21. Bipolar Output Reference

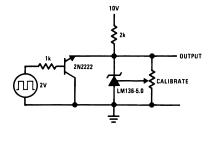
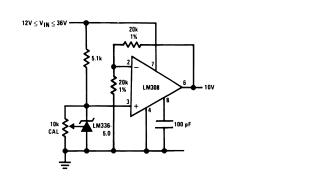


Figure 22. 5.0V Square Wave Calibrator





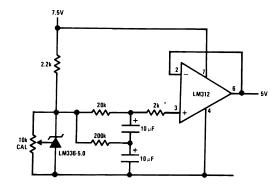


Figure 23. 10V Buffered Reference

Figure 24. Low Noise Buffered Reference

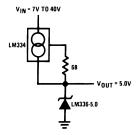
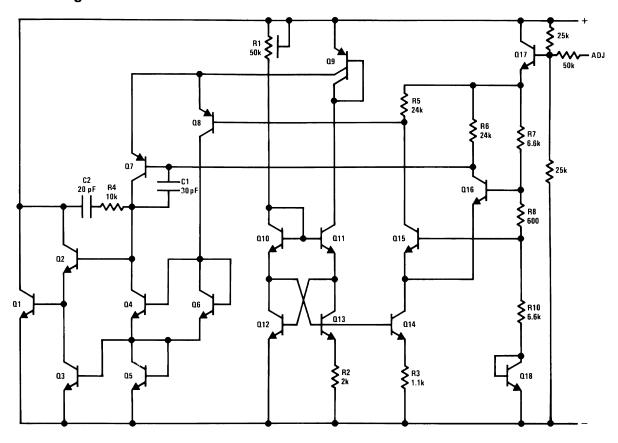


Figure 25. Wide Input Range Reference

Schematic Diagram





REVISION HISTORY

Cr	nanges from Revision C (March 2013) to Revision D	Page
•	Changed layout of National Data Sheet to TI format	

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30-Apr-2024

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LM136-5.0-MW8	ACTIVE	WAFERSALE	YS	0	1	RoHS & Green	Call TI	Level-1-NA-UNLIM	-55 to 125		Samples
LM136AH-5.0	ACTIVE	ТО	NDV	3	1000	Non-RoHS & Green	Call TI	Level-1-NA-UNLIM	-40 to 125	(LM136AH5.0, LM13 6AH5.0)	Samples
LM136AH-5.0/NOPB	ACTIVE	ТО	NDV	3	1000	RoHS & Green	Call TI	Level-1-NA-UNLIM	-40 to 125	(LM136AH5.0, LM13 6AH5.0)	Samples
LM136H-5.0	ACTIVE	ТО	NDV	3	1000	Non-RoHS & Green	Call TI	Level-1-NA-UNLIM	-55 to 125	(LM136H5.0, LM136 H5.0)	Samples
LM136H-5.0/NOPB	ACTIVE	ТО	NDV	3	1000	RoHS & Green	Call TI	Level-1-NA-UNLIM	-55 to 125	(LM136H5.0, LM136 H5.0)	Samples
LM236AH-5.0/NOPB	ACTIVE	ТО	NDV	3	1000	RoHS & Green	Call TI	Level-1-NA-UNLIM	-55 to 125	(LM236AH5.0, LM23 6AH5.0)	Samples
LM236H-5.0	ACTIVE	ТО	NDV	3	1000	Non-RoHS & Green	Call TI	Level-1-NA-UNLIM	-25 to 85	(LM236H5.0, LM236 H5.0)	Samples
LM236H-5.0/NOPB	ACTIVE	ТО	NDV	3	1000	RoHS & Green	Call TI	Level-1-NA-UNLIM	-25 to 85	(LM236H5.0, LM236 H5.0)	Samples
LM336-5 MWC	ACTIVE	WAFERSALE	YS	0	1	RoHS & Green	Call TI	Level-1-NA-UNLIM	-40 to 85		Samples
LM336BM-5.0/NOPB	ACTIVE	SOIC	D	8	95	RoHS & Green	SN	Level-1-260C-UNLIM	0 to 70	LM336 BM5.0	Samples
LM336BMX-5.0/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	SN	Level-1-260C-UNLIM	0 to 70	LM336 BM5.0	Samples
LM336BZ-5.0/NOPB	ACTIVE	TO-92	LP	3	1800	RoHS & Green	Call TI	N / A for Pkg Type	0 to 70	LM336 BZ5.0	Samples
LM336M-5.0/NOPB	ACTIVE	SOIC	D	8	95	RoHS & Green	SN	Level-1-260C-UNLIM	0 to 70	LM336 M5.0	Samples
LM336MX-5.0/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	SN	Level-1-260C-UNLIM	0 to 70	LM336 M5.0	Samples
LM336Z-5.0/NOPB	ACTIVE	TO-92	LP	3	1800	RoHS & Green	Call TI	N / A for Pkg Type	0 to 70	LM336 Z-5.0	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.



PACKAGE OPTION ADDENDUM

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PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	•
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM336BMX-5.0/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM336MX-5.0/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM336BMX-5.0/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM336MX-5.0/NOPB	SOIC	D	8	2500	367.0	367.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE

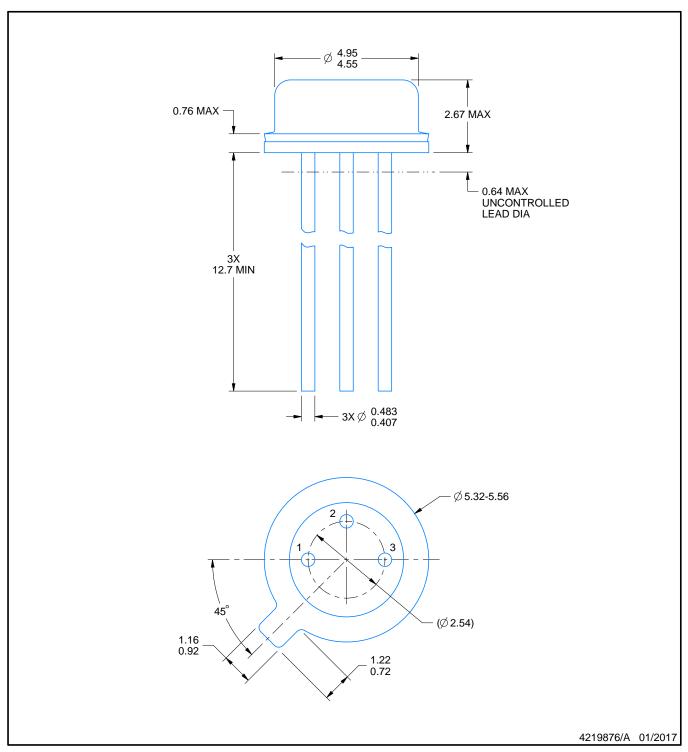


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
LM336BM-5.0/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM336M-5.0	D	SOIC	8	95	495	8	4064	3.05
LM336M-5.0	D	SOIC	8	95	495	8	4064	3.05
LM336M-5.0/NOPB	D	SOIC	8	95	495	8	4064	3.05



TO-46

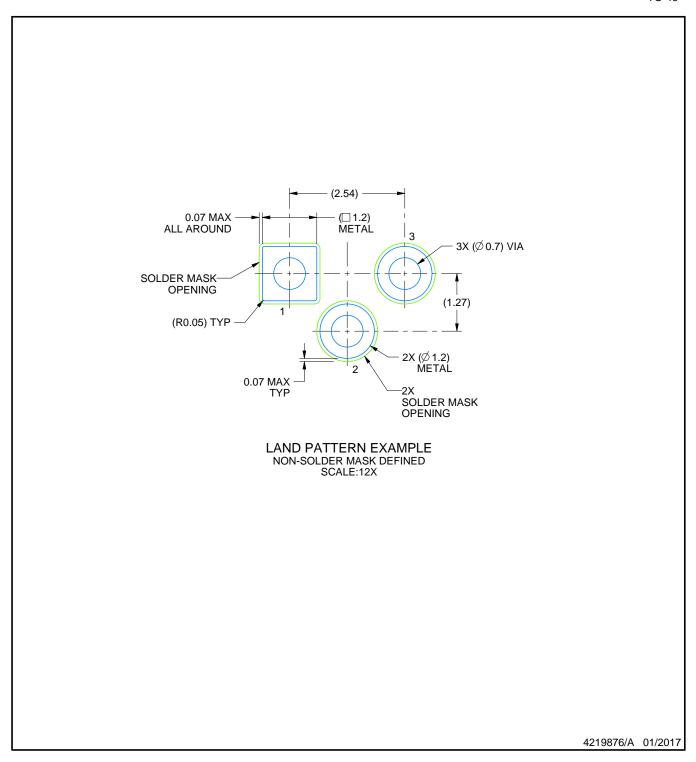


NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC registration TO-46.



TO-46





SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040001-2/F



TO-92 - 5.34 mm max height

TO-92



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.
- 3. Lead dimensions are not controlled within this area.4. Reference JEDEC TO-226, variation AA.
- 5. Shipping method:

 - a. Straight lead option available in bulk pack only.
 b. Formed lead option available in tape and reel or ammo pack.
 - c. Specific products can be offered in limited combinations of shipping medium and lead options.
 - d. Consult product folder for more information on available options.



TO-92





TO-92





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